

0.8%ACCURACY 0.7V OUTPUT 400mA LDO REGULATOR

NO.EA-281-170126

OUTLINE

The RP116Z Series are low voltage 400mA voltage regulator. These ICs had been further improved of low-voltage capability compared with previous low-voltage product.

The input voltage is as low as Min. 1.0V and the output voltage can be set from 0.7V. The output voltage accuracy has been improved to $\pm 0.8\%$ and due to a built-in transistor with low on-resistance of 0.55Ω (at $V_{OUT}=1.5V$).

Each of these ICs consists of a voltage reference unit, an error amplifier, a resistor-net for voltage setting, and a current limit circuits for over-current for the destruction prevention by the over-current.

The CE pin can switch the regulator to standby mode.

The RP116Z is available in the small and thin WLCSP-4-P7 package (0.69mm square, 0.36mm thickness and 0.4mm pitch), consequently providing a high density mounting.

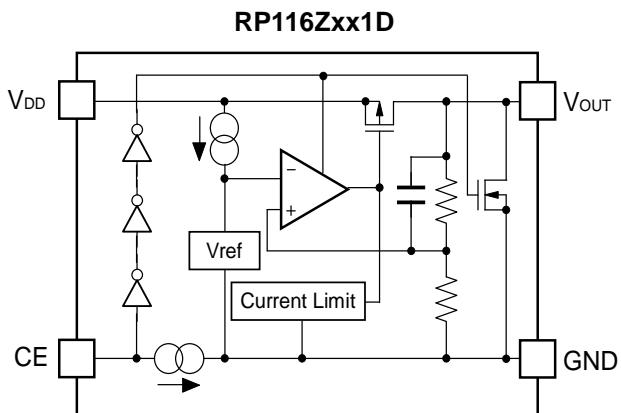
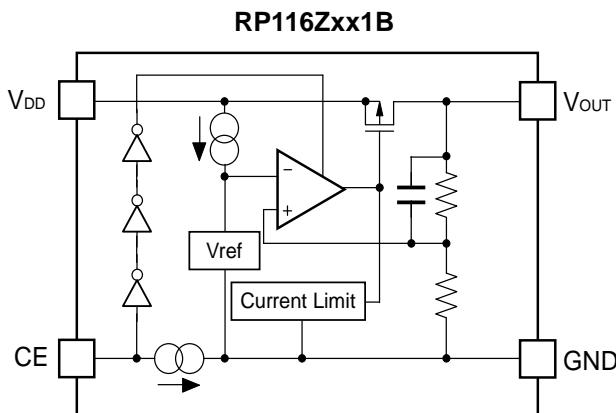
FEATURES

- Supply Current Typ. $48\mu A$
- Standby Current Typ. $0.1\mu A$
- Ripple Rejection Typ. $60dB$ ($f=10kHz$)
- Input Voltage Range $1.0V$ to $3.6V$
- Output Voltage Range $0.7V$ to $1.8V$ (0.1V steps)
(For other voltages, please refer to MARK INFORMATIONS.)
- Output Voltage Accuracy $\pm 0.8\%$ ($V_{OUT} \geq 1.0V$, $T_{opt}=25^\circ C$)
- Temperature-Drift Coefficient of Output Voltage ... Typ. $\pm 60ppm/^{\circ}C$
- Dropout Voltage Typ. $0.22V$ ($V_{OUT}=1.5V$)
- Line Regulation Typ. $0.10\%/V$
- Package WLCSP-4-P7
- Built-in Fold Back Protection Circuit Typ. $110mA$ (Current at short mode)
- Built-in Constant Slope Circuit
- Ceramic capacitors are recommended to be used with this IC $1.0\mu F$ or more

APPLICATIONS

- Power source for portable communication equipment.
- Power source for electrical appliances such as cameras, VCRs and camcorders.
- Power source for battery-powered equipment.

BLOCK DIAGRAMS



SELECTION GUIDE

The output voltage, auto discharge function for the ICs can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP116Zxx1*-TR-F	WLCSP-4-P7	5,000 pcs	Yes	Yes

xx: Setting Output Voltage (V_{OUT}) :

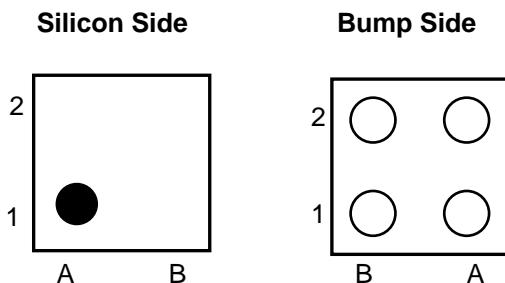
Fixed Type: 07 to 18 Stepwise setting with 0.1V increment in the range from 0.7V to 1.8V
Exception: 1.25V=RP116Z121x5-TR-F
1.85V=RP116Z181x5-TR-F

* : Designation of Active Type:

B : "H" Active, without auto discharge function at off state.
D : "H" Active, with auto discharge function at off state.

PIN CONFIGURATIONS

- WLCSP-4-P7



PIN DESCRIPTIONS

- WLCSP-4-P7

Pin No	Symbol	Pin Description
A1	V_{DD}	Input Pin
A2	V_{OUT}	Output Pin
B1	CE	Chip Enable Pin ("H" Active)
B2	GND	Ground Pin

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	4.0	V
V_{CE}	Input Voltage (CE Pin)	-0.3 to 4.0	V
V_{OUT}	Output Voltage	-0.3 to $V_{IN}+0.3$	V
I_{OUT}	Output Current	500	mA
P_D	Power Dissipation (WLCSP-4-P7)*	278	mW
T_{opt}	Operating Temperature Range	-40 to 85	°C
T_{stg}	Storage Temperature Range	-55 to 125	°C

*) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

ELECTRICAL CHARACTERISTICS

- RP116Z

V_{IN} =Set $V_{OUT}+1V$, $I_{OUT}=1mA$, $C_{IN}=C_{OUT}=1\mu F$, unless otherwise noted.

The specifications surrounded by are guaranteed by Design Engineering at $-40^{\circ}C \leq Ta \leq 85^{\circ}C$.

(Ta=25°C)							
Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
V_{OUT}	Output Voltage	Ta=25°C	$V_{OUT} \geq 1.0V$	x 0.992		x 1.008	V
			$V_{OUT} < 1.0V$	-8		+8	mV
		$-40^{\circ}C \leq Ta \leq 85^{\circ}C$	$V_{OUT} \geq 1.0V$	x 0.983		x 1.017	V
			$V_{OUT} < 1.0V$	[17]		[+17]	mV
I_{OUT}	Output Current			400			mA
$\Delta V_{OUT} / \Delta I_{OUT}$	Load Regulation	$1mA \leq I_{OUT} \leq 400mA$			25	[45]	mV
V_{DIF}	Dropout Voltage	Please see the table on next page					
I_{SS}	Supply Current	$I_{OUT}=0mA$			48	75	μA
Istandby	Supply Current (Standby)	$V_{CE}=0V$			0.1	8.0	μA
$\Delta V_{OUT} / \Delta V_{IN}$	Line Regulation	Set $V_{OUT}+0.5V \leq V_{IN} \leq 3.6V$ In case Set $V_{OUT}<0.8V$, $1.3V \leq V_{IN} \leq 3.6V$			0.10	[0.25]	%/V
RR	Ripple Rejection	$f=10kHz$ Ripple 0.2Vp-p V_{IN} =Set $V_{OUT}+1.0V$ $I_{OUT}=30mA$			60		dB
V_{IN}	Input Voltage			1.0		[3.6]	V
$\Delta V_{OUT} / \Delta T_a$	Output Voltage Temperature Coefficient	$-40^{\circ}C \leq Ta \leq 85^{\circ}C$			± 60		ppm/ $^{\circ}C$
I_{SC}	Short Current Limit	$V_{OUT}=0V$			110		mA
I_{PD}	CE Pull-down Current				0.38	[0.7]	μA
V_{CEH}	CE Input Voltage "H"			0.9			V
V_{CEL}	CE Input Voltage "L"					[0.4]	V
en	Output Noise	$BW=10Hz$ to $100kHz$ $I_{OUT}=30mA$ $V_{OUT}=0.7V$			30		μV_{rms}
R_{LOW}	Low Output Nch Tr. ON Resistance (D version Only)	$V_{IN}=2.0V$ $V_{CE}=0V$			43		Ω

All test items listed under Electrical Characteristics are done under the pulse load condition ($T_j \approx Ta = 25^{\circ}C$) except Output Noise, Ripple Rejection and Output Voltage Temperature Coefficient items.

The specifications surrounded by are guaranteed by Design Engineering at $-40^{\circ}\text{C} \leq T_a \leq 85^{\circ}\text{C}$.

• Dropout Voltage by Output Voltage

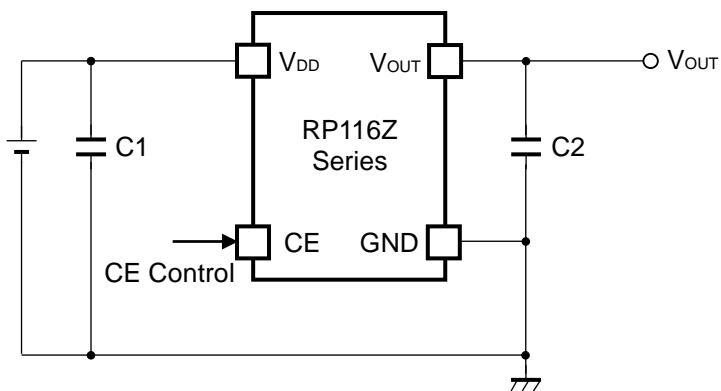
(Ta=25°C)

Output Voltage V _{OUT} (V)	Dropout Voltage V _{DIF} (V)		
	Condition	Typ.	Max.
0.7 ≤ V _{OUT} < 0.8	I _{OUT} =400mA	0.48	0.62
0.8 ≤ V _{OUT} < 0.9		0.40	0.54
0.9 ≤ V _{OUT} < 1.0		0.36	0.47
1.0 ≤ V _{OUT} < 1.2		0.32	0.45
1.2 ≤ V _{OUT} < 1.5		0.28	0.38
1.5 ≤ V _{OUT}		0.22	0.31

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

TYPICAL APPLICATION



(External Components)

C1, C2 Ceramic 1.0 μ F MURATA: GRM155B31A105KE15

TECHNICAL NOTES

When using these ICs, consider the following points:

Phase Compensation

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a capacitor C2 with 1.0 μ F or more.

If a tantalum capacitor is used, and its ESR (Equivalent Series Resistance) of C2 is large, the loop oscillation may result. Because of this, select C2 carefully considering its frequency characteristics.

PCB Layout

Make V_{DD} and GND lines sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect a capacitor C1 with a capacitance value as much as 1.0 μ F or more between V_{DD} and GND pin, and as close as possible to the pins.

Set external components, especially the output capacitor C2, as close as possible to the ICs, and make wiring as short as possible.

Impedance of Input pin

CE pull-down constant current circuit is built in the RP116Z.

However, if the CE pin is floating and the wiring is long, the malfunction may occur by noise. Therefore, fully evaluation on the actual PCB is necessary.

CONSTANT SLOPE CIRCUITS

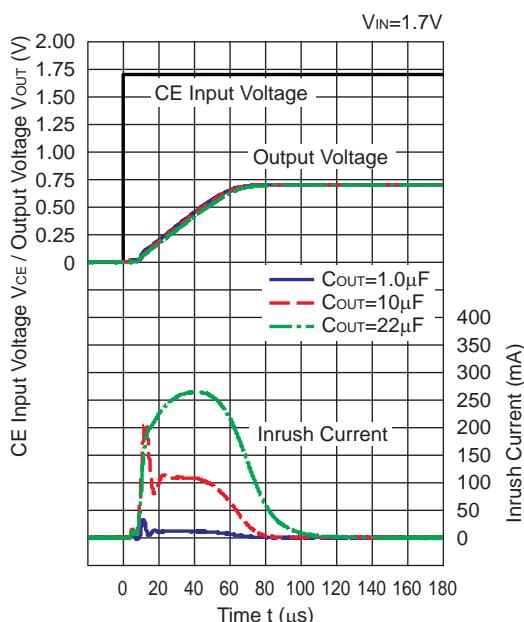
The RP116Z Series is equipped with a constant slope circuit as a soft-start circuit, which allows the output voltage to start up gradually when the CE is turned on.

The constant slope circuit minimizes the inrush current at the start-up and also prevents the overshoot of the output voltage.

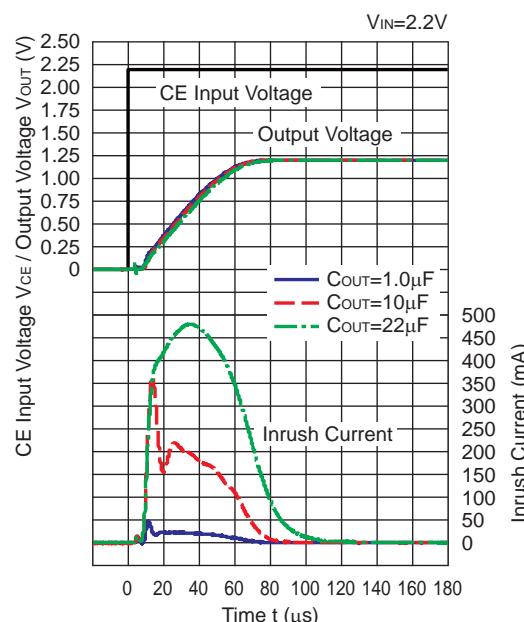
The capacitor to create the start-up slope is built in the IC that does not require any external components. The start-up time and the start-up slope angle are fixed inside the IC. For more details, please refer to the graph 15 of "Inrush Current Characteristics Example".

Inrush Current Characteristics Example (C1=1.0 μ F, T_{opt}=25°C)

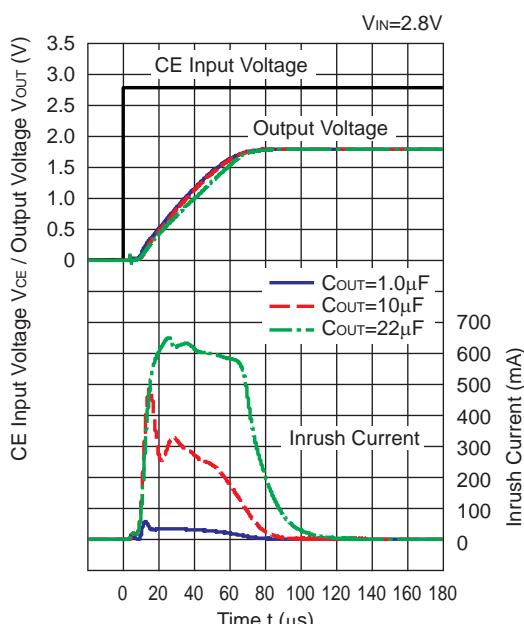
RP116Z071B/D



RP116Z121B/D



RP116Z181B/D



PACKAGE INFORMATION

- Power Dissipation (WLCSP-4-P7)

Power Dissipation (P_D) depends on conditions of mounting on board. This specification is based on the measurement at the condition below:

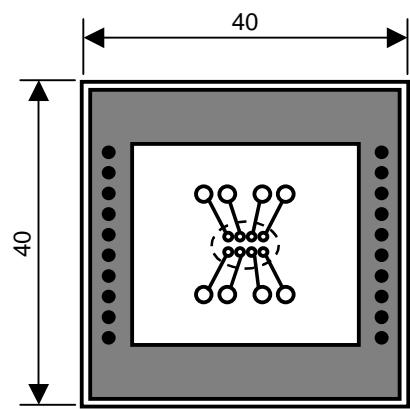
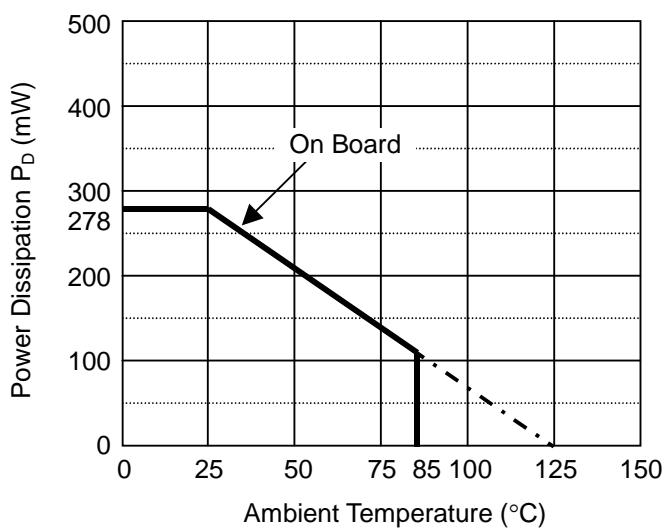
Measurement Conditions

	Standard Land Pattern
Environment	Mounting on Board (Wind velocity=0m/s)
Board Material	Glass cloth epoxy plastic (Double sided)
Board Dimensions	40mm x 40mm x 1.6mm
Copper Ratio	Top side : Approx. 50% , Back side : Approx. 50%
Through-hole	Ø 0.5mm x 28pcs

Measurement Result

($T_a=25^{\circ}\text{C}$, $T_{jmax}=125^{\circ}\text{C}$)

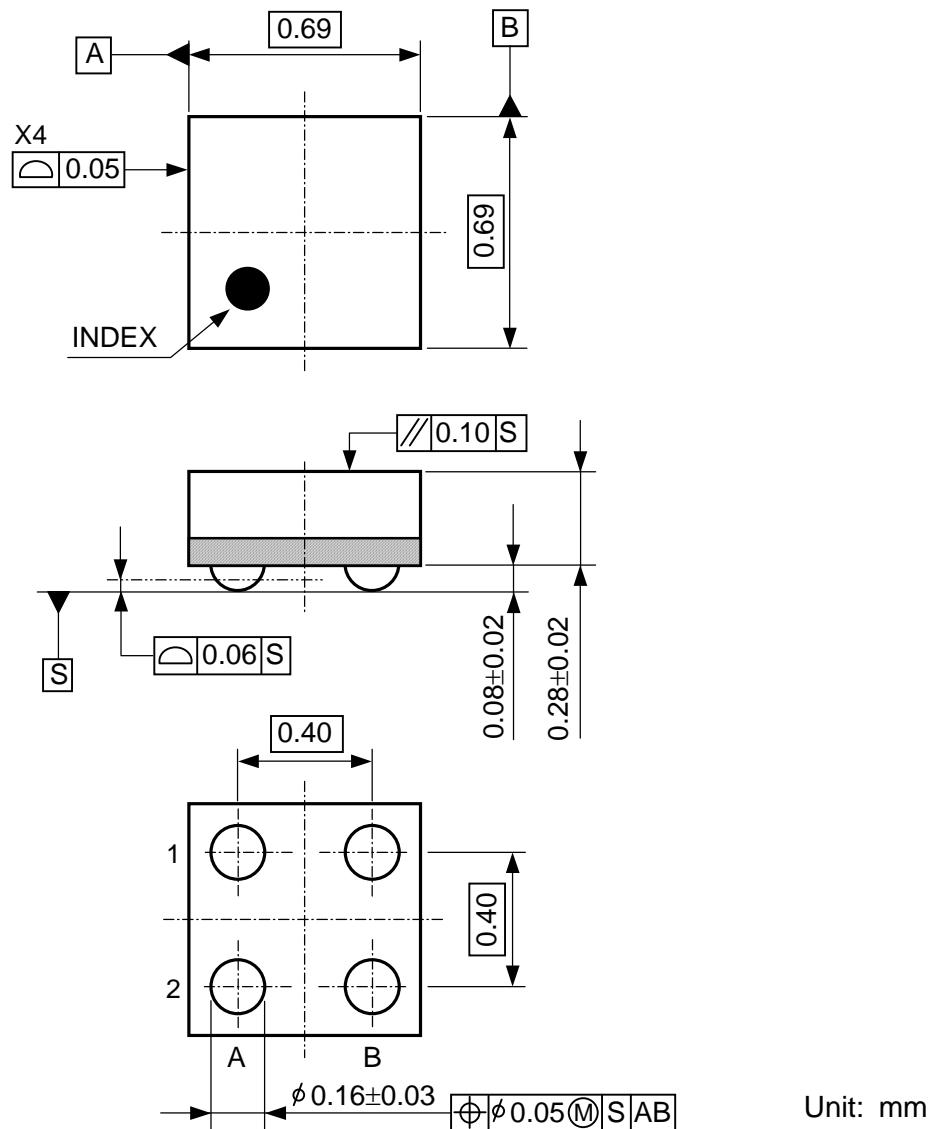
	Standard Land Pattern
Power Dissipation	278mW
Thermal Resistance	$\theta_{ja} = (125-25)^{\circ}\text{C}/0.278\text{W} = 360^{\circ}\text{C/W}$ $\theta_{jc} = 46^{\circ}\text{C/W}$



Measurement Board Pattern

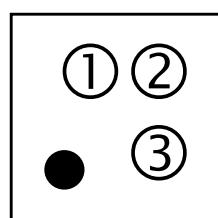
IC Mount Area (Unit : mm)

• Package Dimensions (WLCSP-4-P7)



• Mark Specifications (WLCSP-4-P7)

- ① : Product Code ... **A**
- ②③ : Lot No ... Alphanumeric serial number.



RP116Z

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- RP116Z Series marking list table (WLCSP-4-P7)

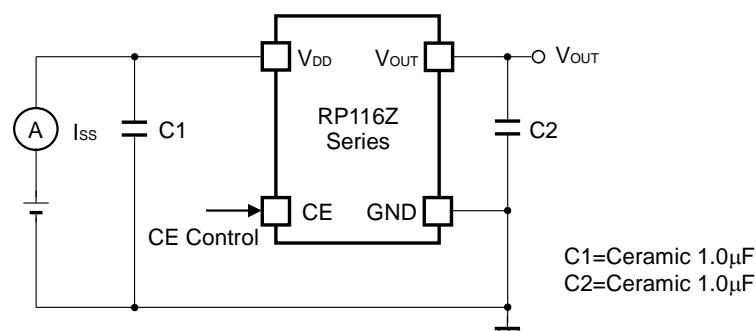
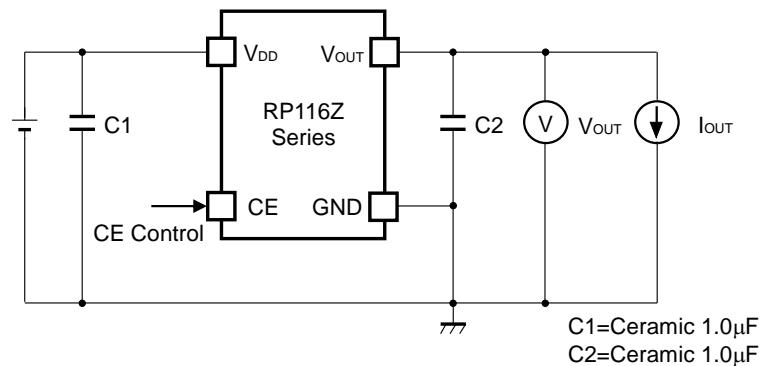
●RP116Zxx1B

Product Name	V _{SET}
RP116Z071B	0.7V
RP116Z081B	0.8V
RP116Z091B	0.9V
RP116Z101B	1.0V
RP116Z111B	1.1V
RP116Z121B	1.2V
RP116Z131B	1.3V
RP116Z141B	1.4V
RP116Z151B	1.5V
RP116Z161B	1.6V
RP116Z171B	1.7V
RP116Z181B	1.8V
RP116Z121B5	1.25V
RP116Z181B5	1.85V

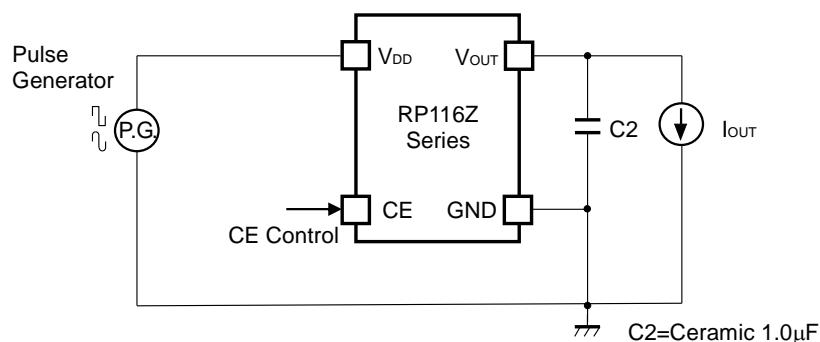
●RP116Zxx1D

Product Name	V _{SET}
RP116Z071D	0.7V
RP116Z081D	0.8V
RP116Z091D	0.9V
RP116Z101D	1.0V
RP116Z111D	1.1V
RP116Z121D	1.2V
RP116Z131D	1.3V
RP116Z141D	1.4V
RP116Z151D	1.5V
RP116Z161D	1.6V
RP116Z171D	1.7V
RP116Z181D	1.8V
RP116Z121D5	1.25V
RP116Z181D5	1.85V

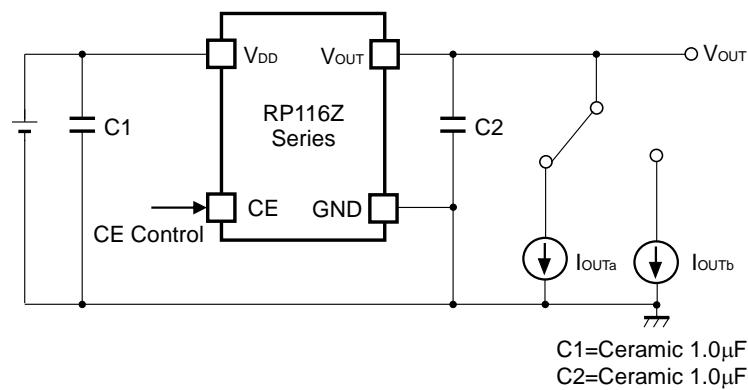
TEST CIRCUITS



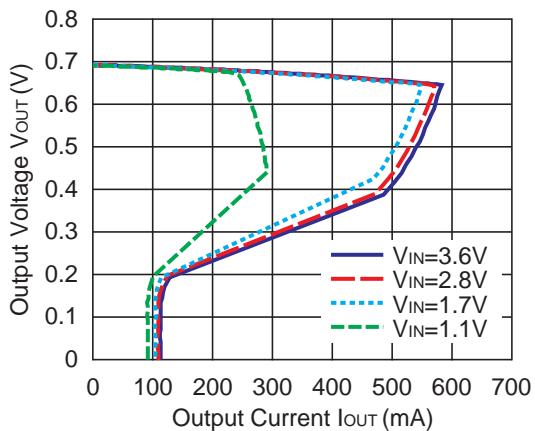
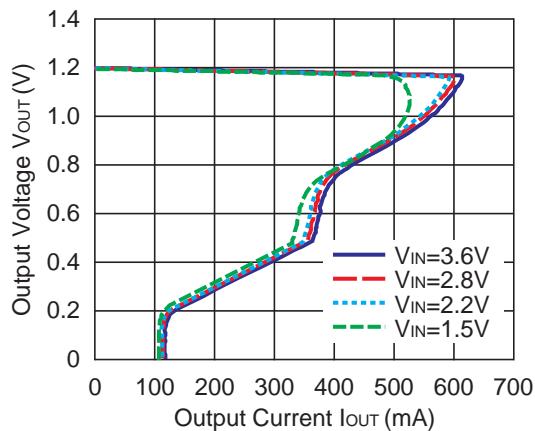
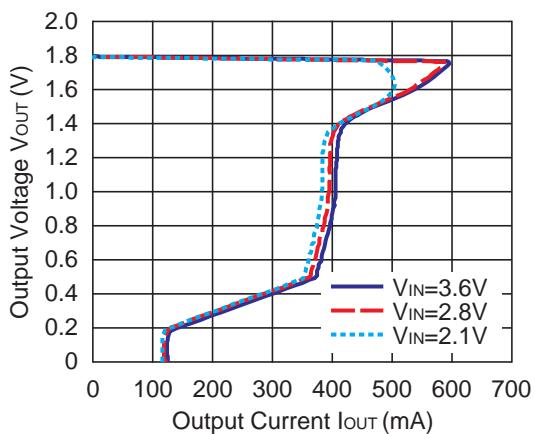
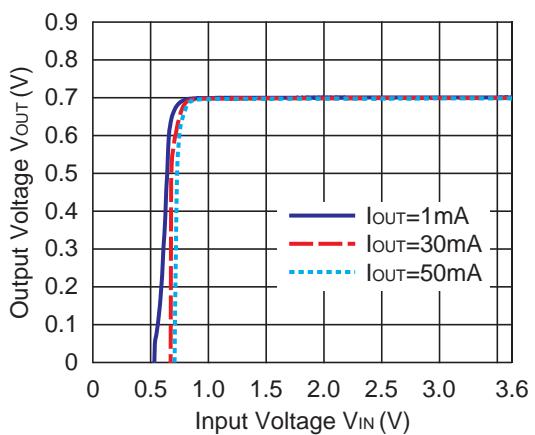
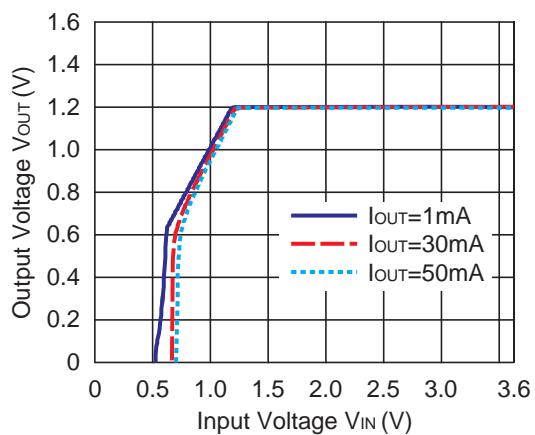
Supply Current Test Circuit



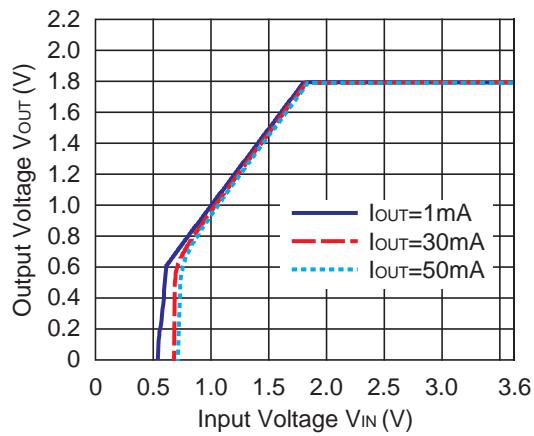
Ripple Rejection Test Circuit



Load Transient Response Test Circuit

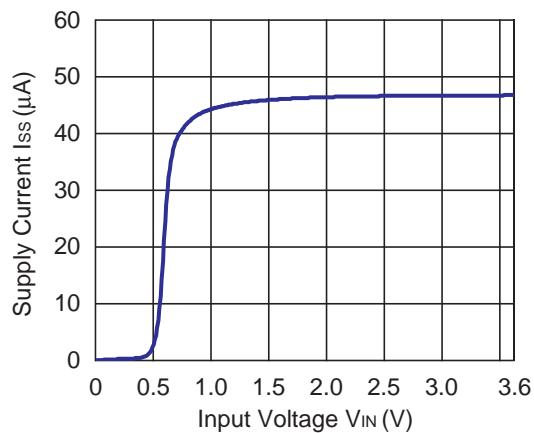
TYPICAL CHARACTERISTICS**1) Output Voltage vs. Output Current ($T_{opt}=25^{\circ}\text{C}$)****RP116Z071x****RP116Z121x****RP116Z181x****2) Output Voltage vs. Input Voltage ($T_{opt}=25^{\circ}\text{C}$)****RP116Z071x****RP116Z121x**

RP116Z181x

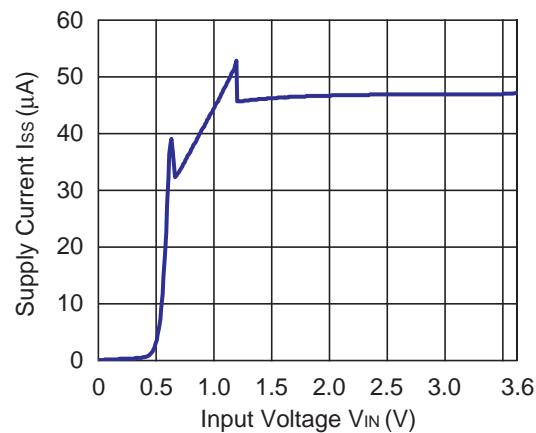


3) Supply Current vs. Input Voltage ($T_{opt}=25^{\circ}\text{C}$)

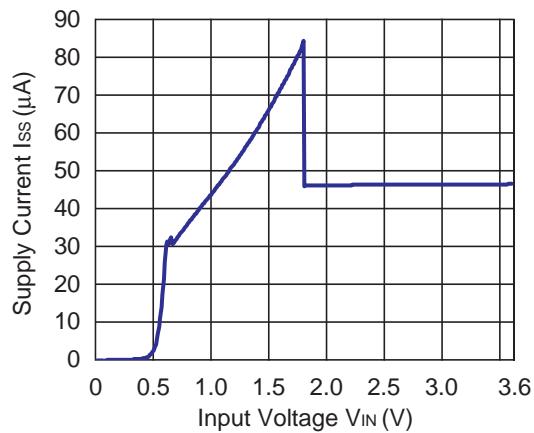
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RP116Z121x



RP116Z181x

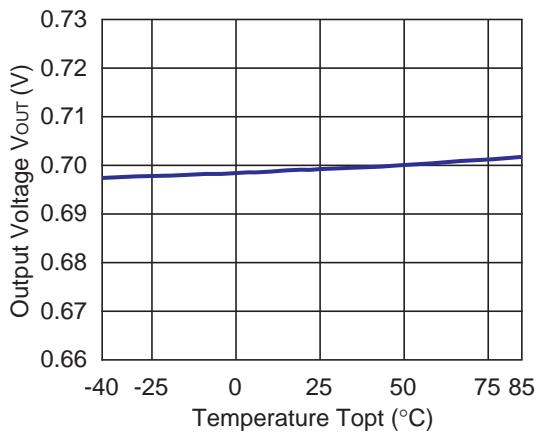


RP116Z

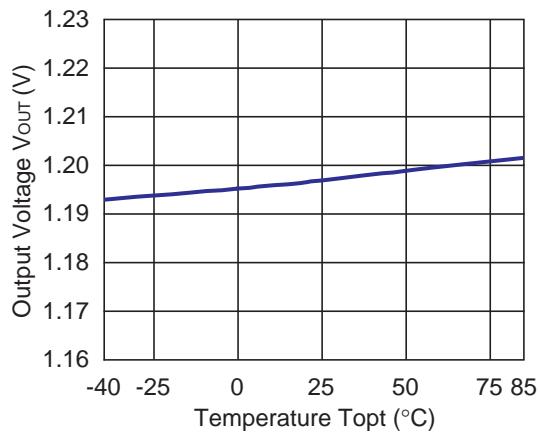
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4) Output Voltage vs. Temperature

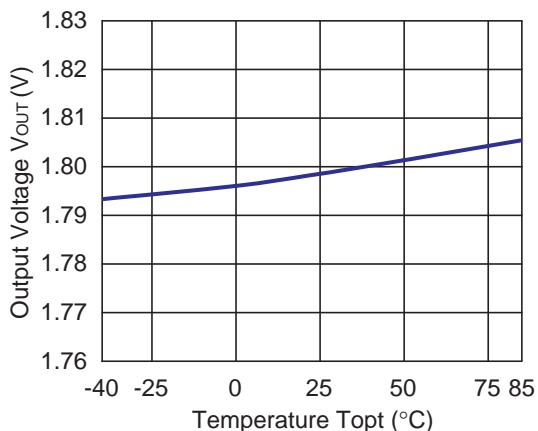
RP116Z071x



RP116Z121x

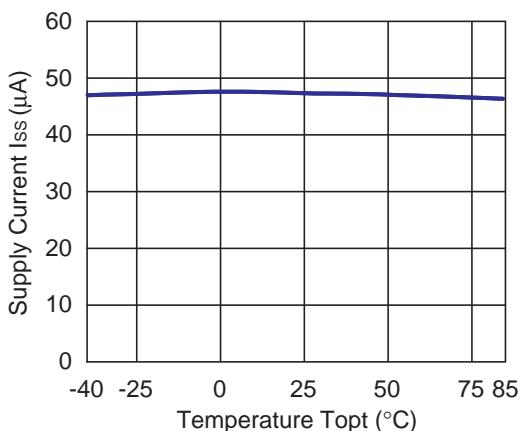


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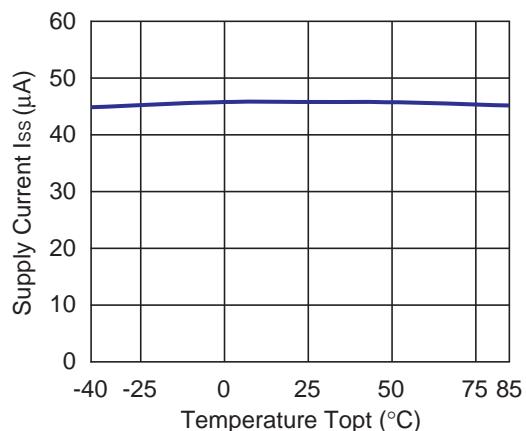


5) Supply Current vs. Temperature

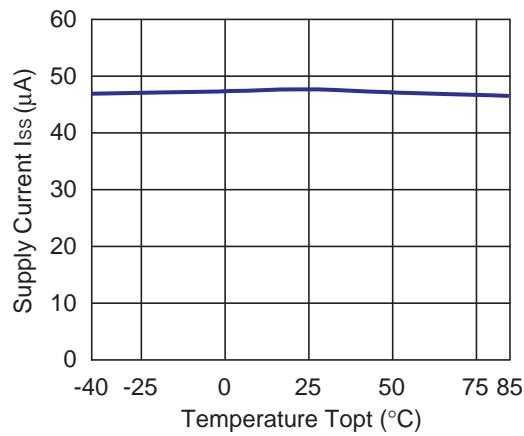
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RP116Z121x

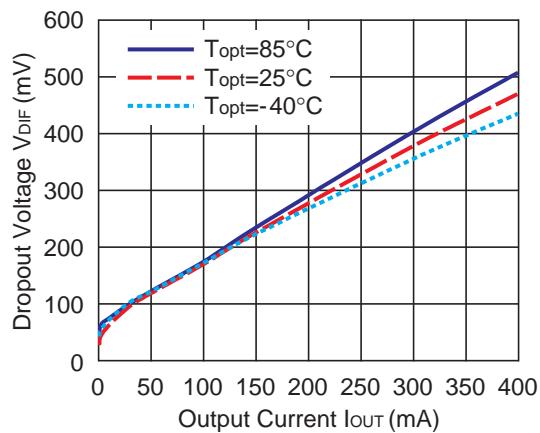


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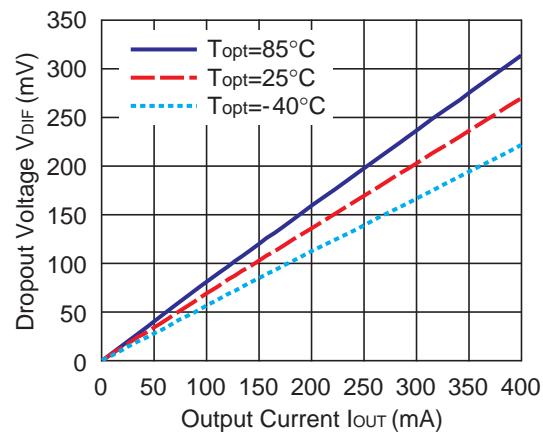


6) Dropout Voltage vs. Output Current

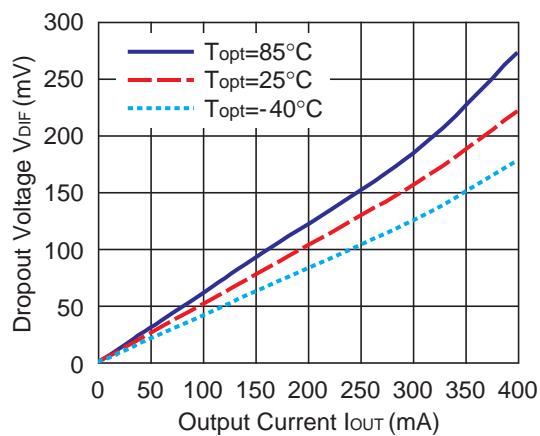
RP116Z071x



RP116Z121x

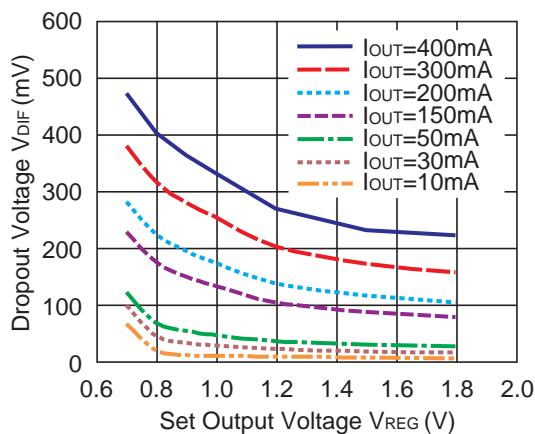
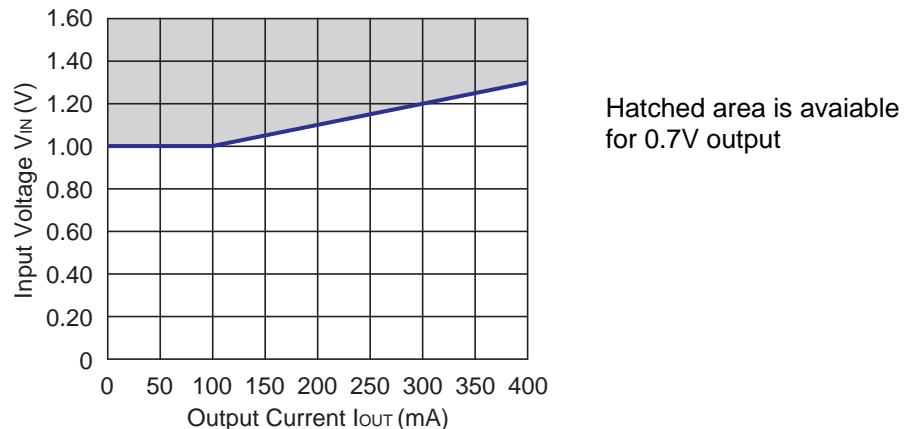
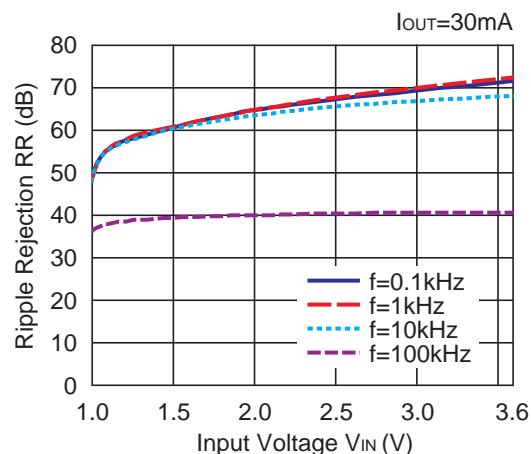
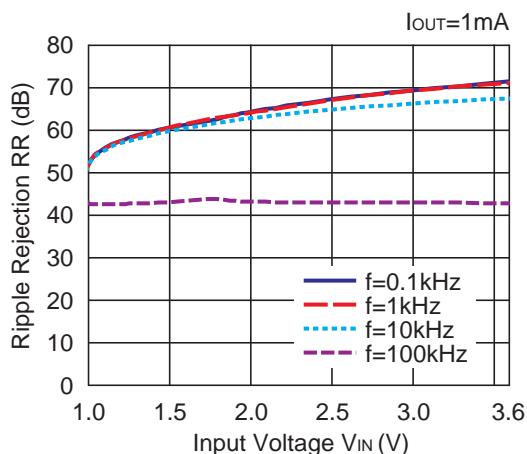


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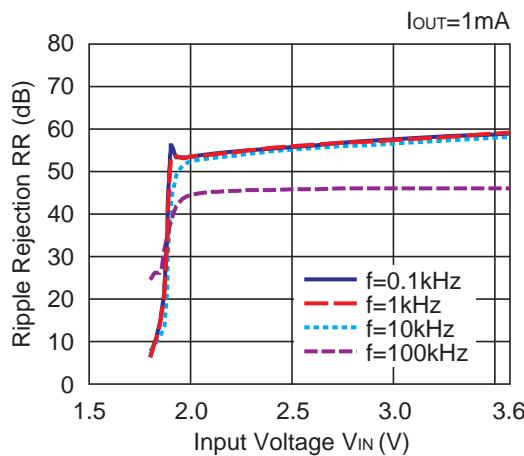


RP116Z

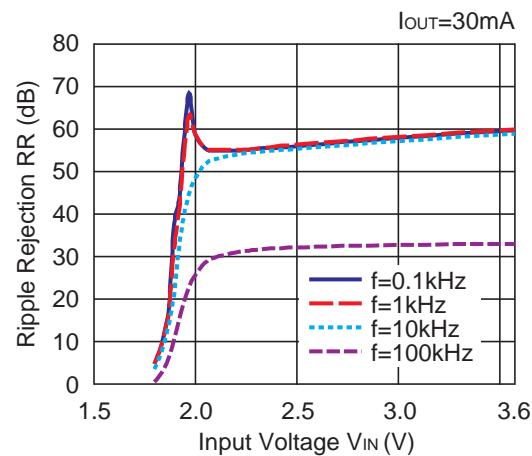
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7) Dropout Voltage vs Set Output Voltage ($T_{opt}=25^{\circ}\text{C}$)**8) Minimum Operating Voltage****RP116Z071x****9) Ripple Rejection vs. Input Bias Voltage ($C_1=\text{none}$, $C_2=1.0\mu\text{F}$, Ripple=0.2Vp-p, $T_{opt}=25^{\circ}\text{C}$)****RP116Z071x****RP116Z071x**

RP116Z181x

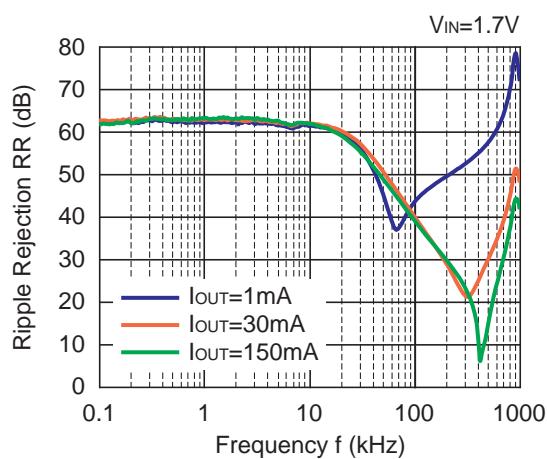


RP116Z181x

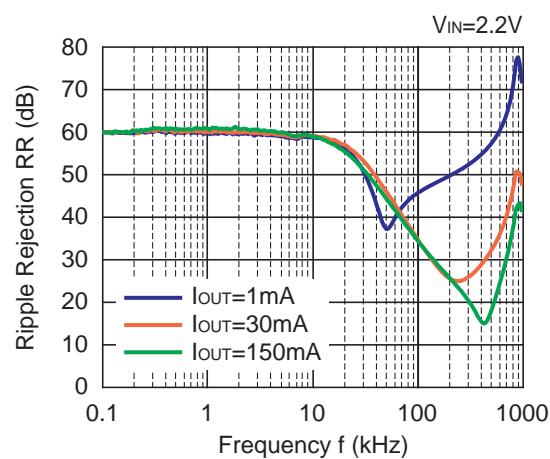


10) Ripple Rejection vs. Frequency ($C_1=\text{none}$, $C_2=1.0\mu\text{F}$, Ripple=0.1Vp-p, $T_{opt}=25^\circ\text{C}$)

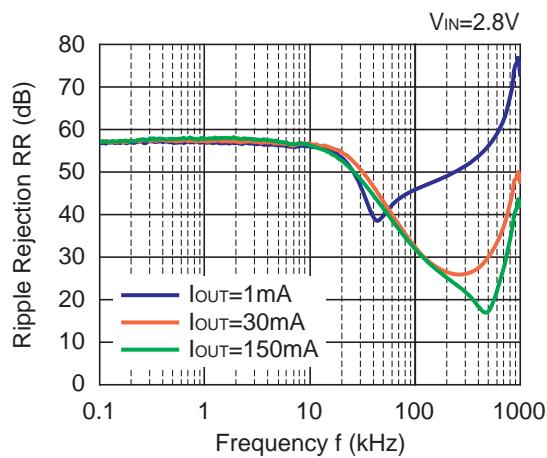
RP116Z071x

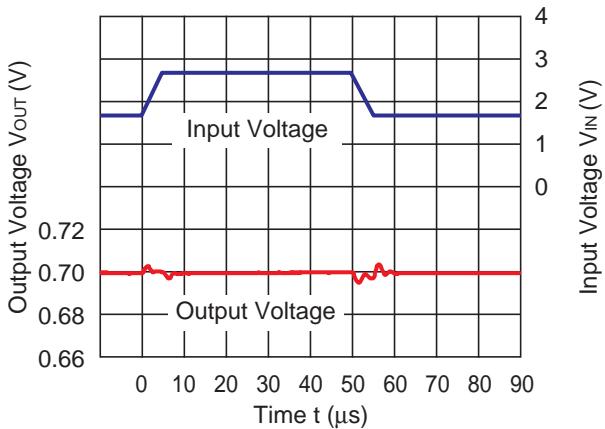
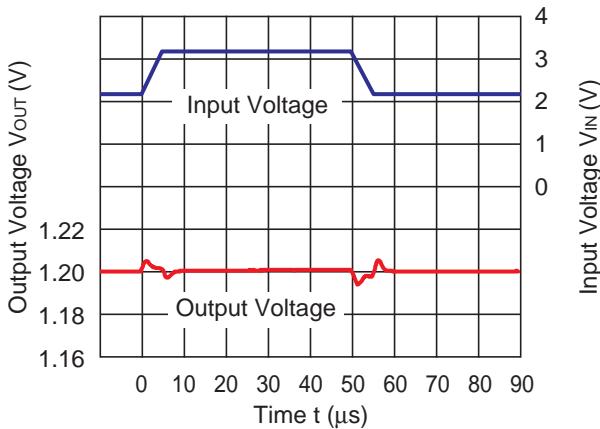
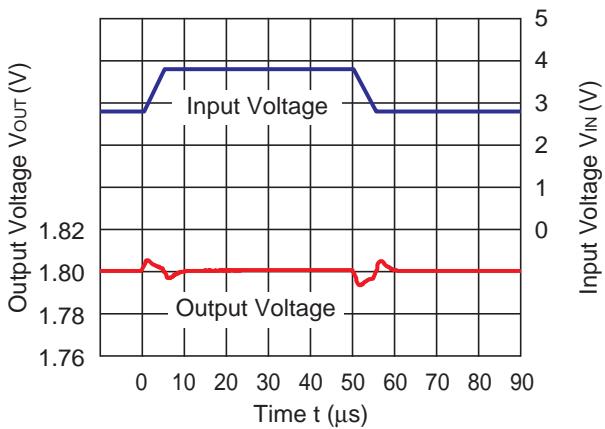
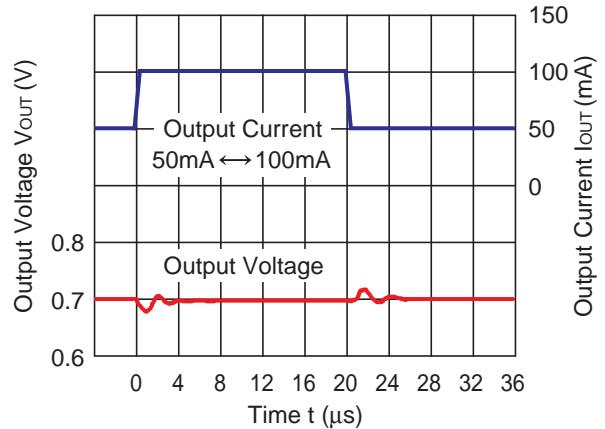
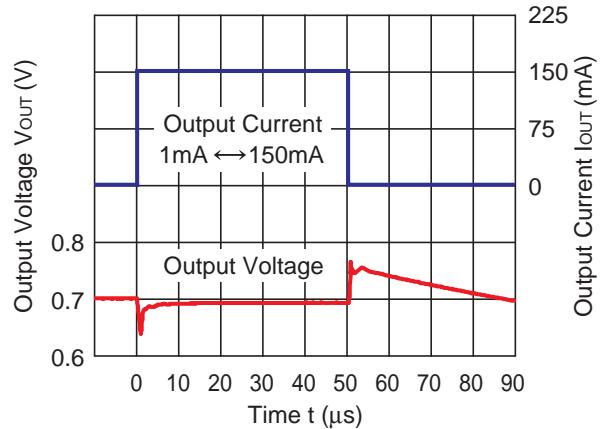


RP116Z121x

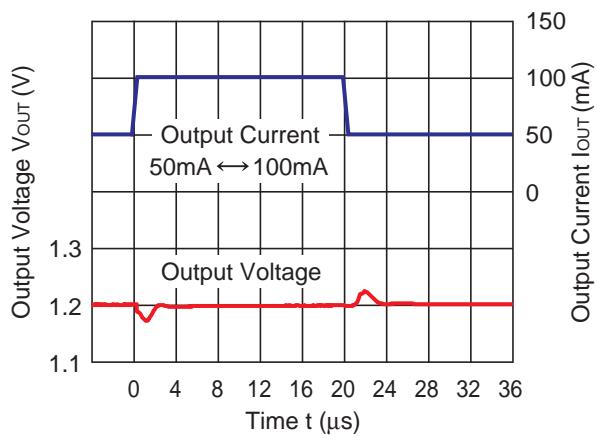


RP116Z181x

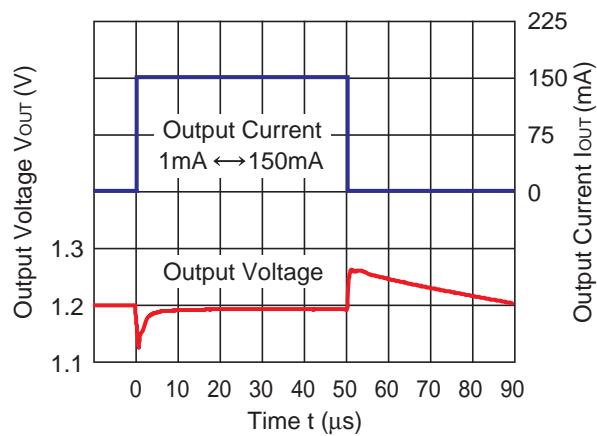


11) Input Transient Response (C1=none, C2=1.0 μ F, I_{OUT}=30mA, tr=tf=5 μ s, T_{opt}=25°C)**RP116Z071x****RP116Z121x****RP116Z181x****12) Load Transient Response (C1=C2=1.0 μ F, tr=tf=5 μ s, T_{opt}=25°C)****RP116Z071x****RP116Z071x**

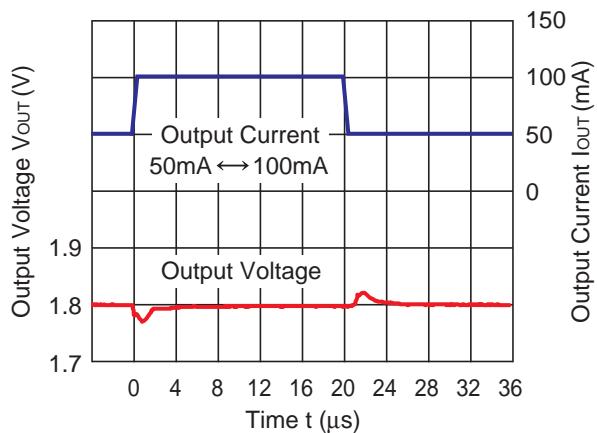
RP116Z121x



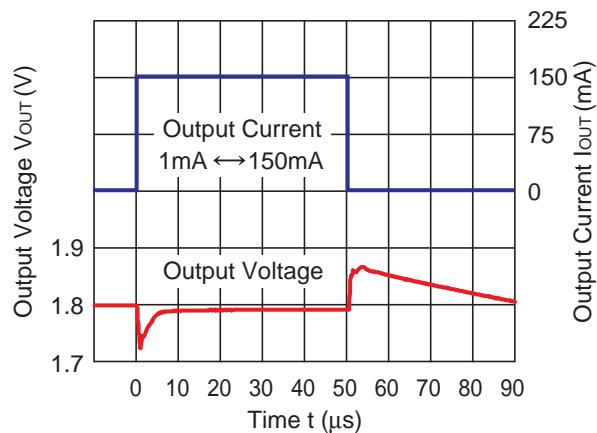
RP116Z121x



RP116Z181x

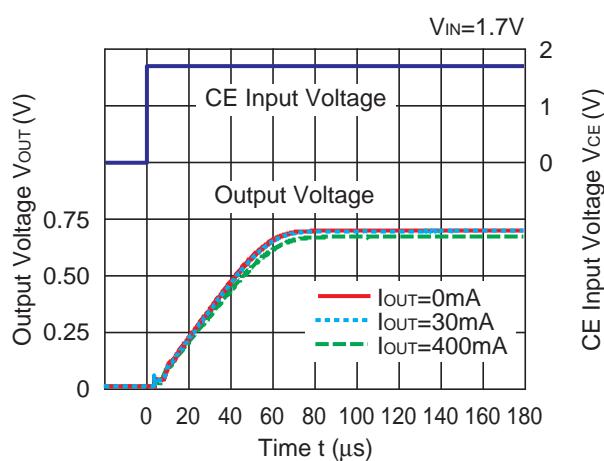


RP116Z181x

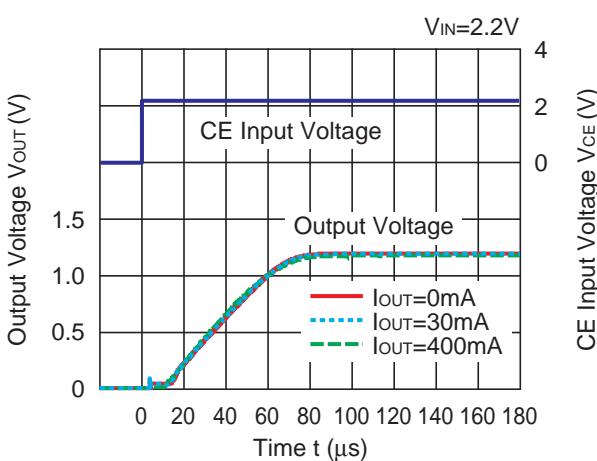


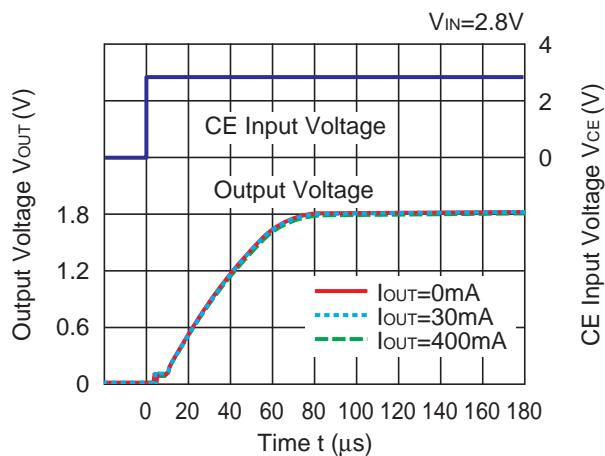
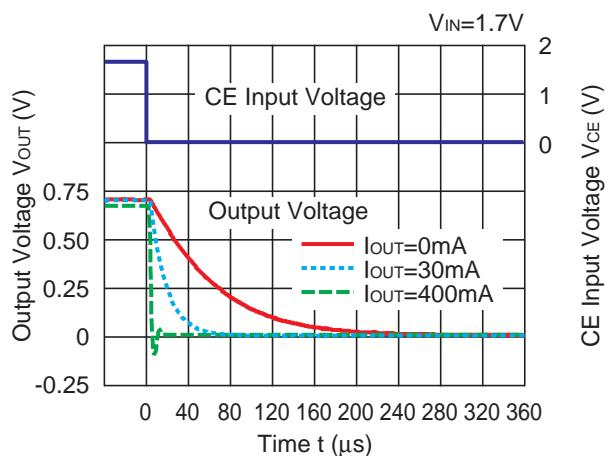
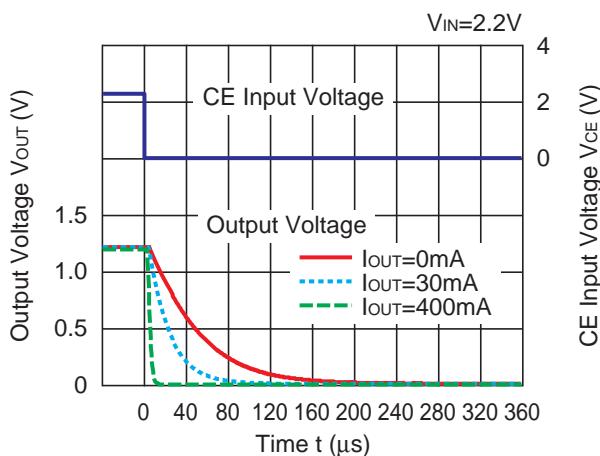
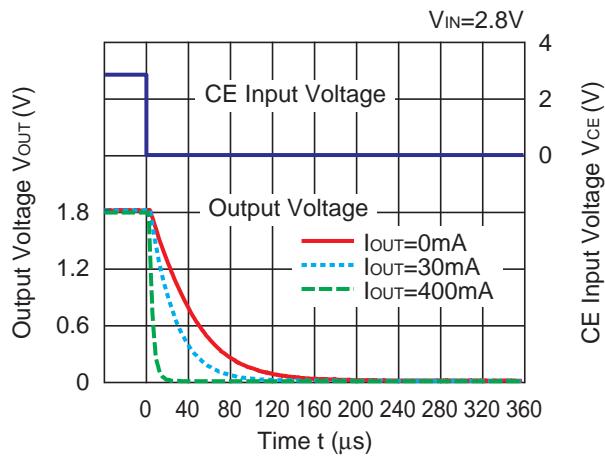
13) Turn On Speed with CE pin ($C_1=C_2=1.0\mu F$, $T_{opt}=25^\circ C$)

RP116Z071x



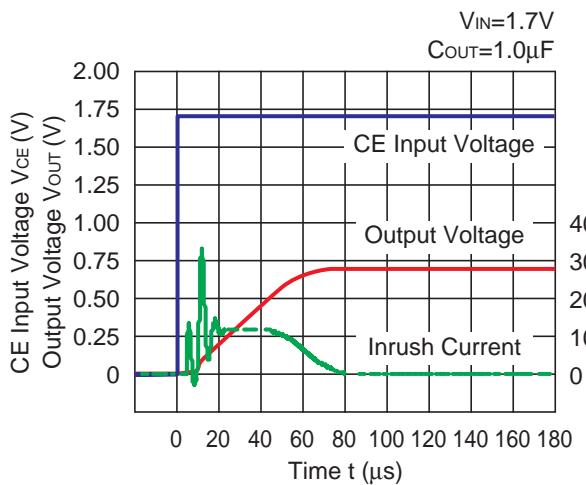
RP116Z121x



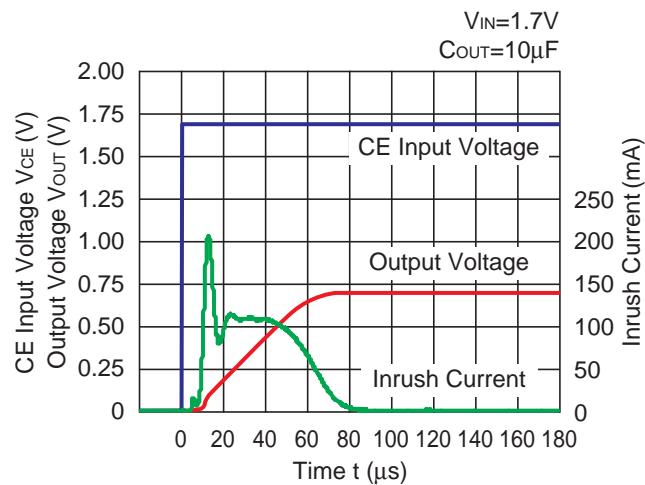
RP116Z181x**14) Turn Off Speed with CE pin ($C_1=C_2=1.0\mu F$, $T_{opt}=25^\circ C$)****RP116Z071x****RP116Z121x****RP116Z181x**

15) Inrush Current at Start up ($C_1=1.0\mu F$, $T_{opt}=25^\circ C$)

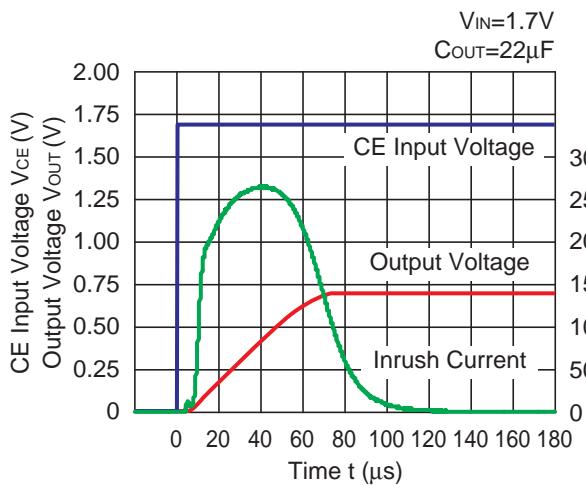
RP116Z071x



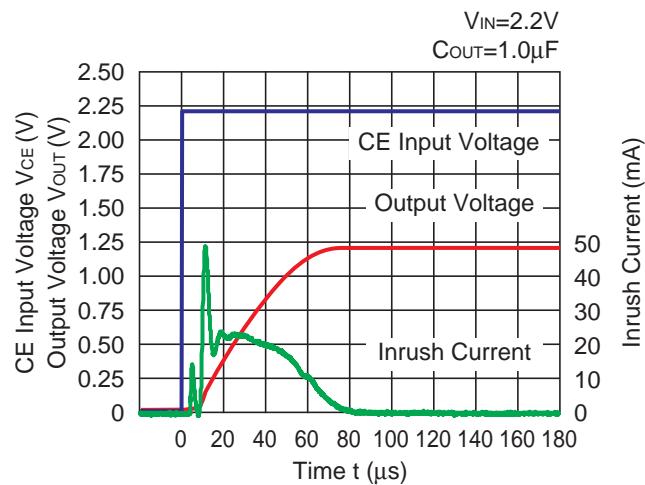
RP116Z071x



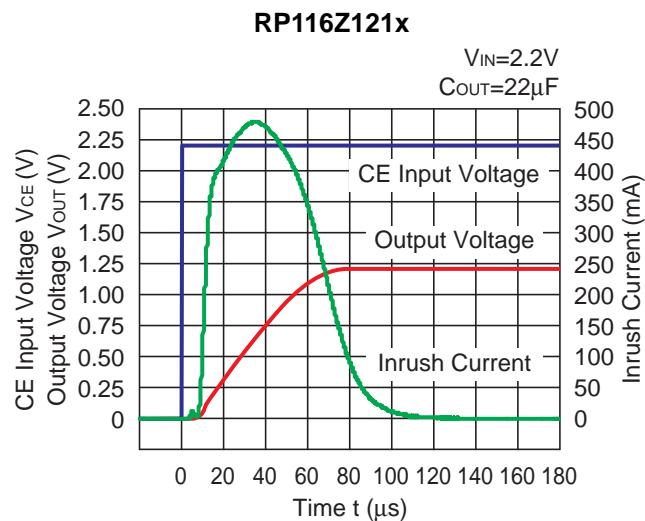
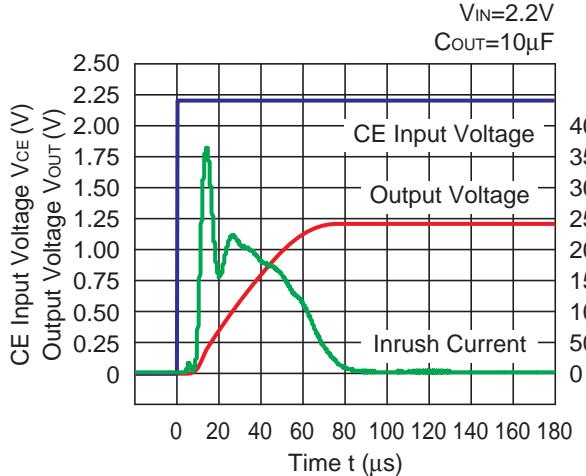
RP116Z071x



RP116Z121x



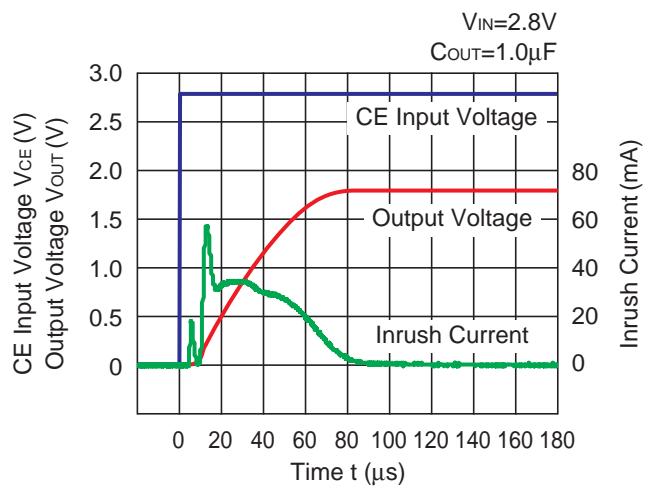
RP116Z121x



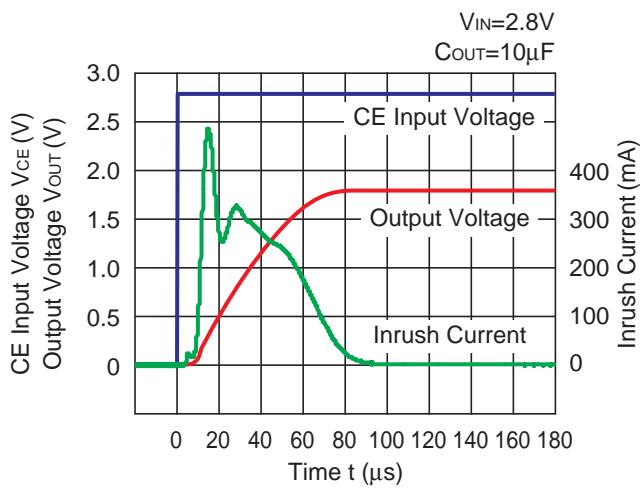
RP116Z

NO.EA-281-170126

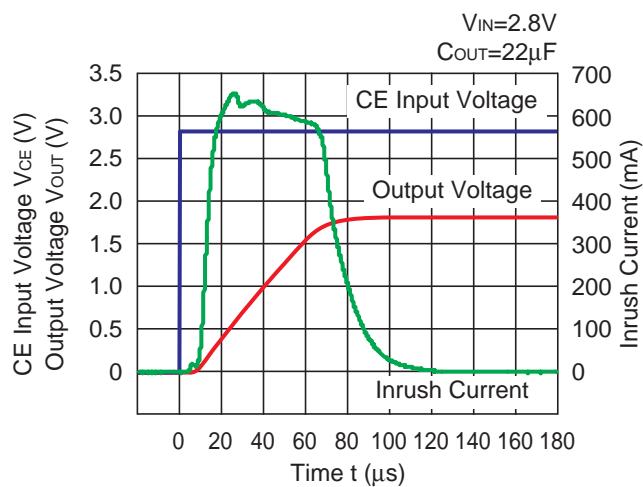
RP116Z181x



RP116Z181x



RP116Z181x



ESR vs. Output Current

When using these ICs, consider the following points:

The relations between I_{OUT} (Output Current) and ESR of an output capacitor are shown below.

The conditions when the white noise level is under $40\mu V$ (Avg.) are marked as the hatched area in the graph.

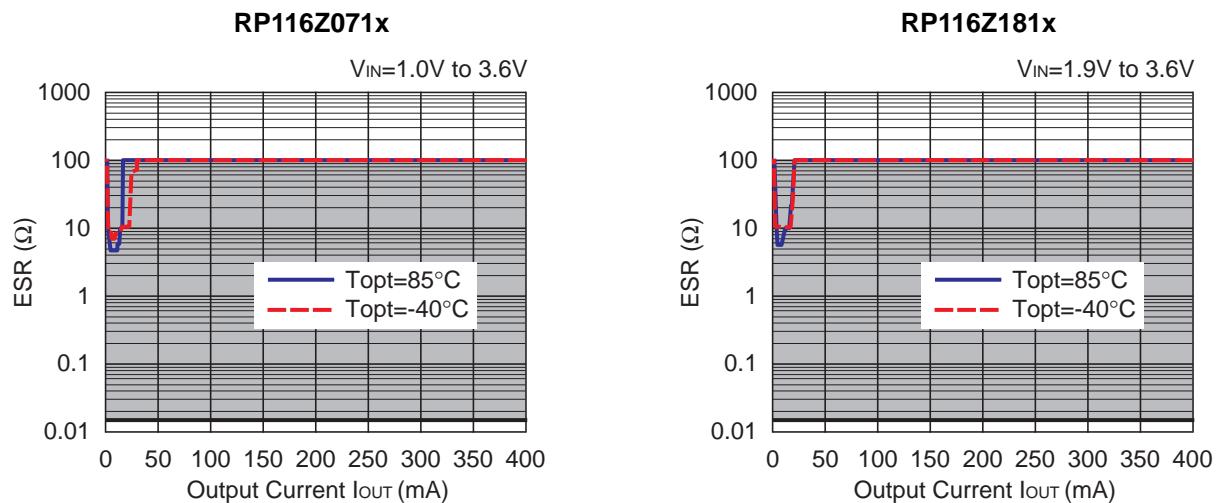
Measurement conditions

Frequency Band: 10Hz to 3MHz

Temperature : $-40^{\circ}C$ to $85^{\circ}C$

C1, C2 : $1.0\mu F$ MURATA GRM155B31A105KE15

If other than ceramic capacitors such as tantalum, the ESR of the capacitor might be higher than expected. This graph shows the stable area with ESR limit. In the actual evaluation, we used Murata GRM155B31A105KE15, therefore, bias characteristics of the same kind of ceramic capacitors are considered.





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10. There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or our distributor before attempting to use AOI.
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